NSR0320XV6T1

Schottky Barrier Diode

These Schottky barrier diodes are designed for high current, handling capability, and low forward voltage performance.

Features

- Low Forward Voltage 0.35 V (Typ) @ $I_F = 10 \text{ mAdc}$
- High Current Capability
- These are Pb-Free Devices

MAXIMUM RATINGS ($T_J = 125^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Voltage	V _R	23	V
Forward Power Dissipation @ T _A = 25°C Derate above 25°C	P _F	200 2.0	mW mW/°C
Forward Current (DC) – Continuous	I _F	1	Α
Forward Current t = 8.3 ms Half Sinewave; JEDEC Method	I _F	7.5	Α
Junction Temperature	TJ	125 Max	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Total Capacitance (V _R = 5.0 V, f = 1.0 MHz)	C _T	1	30	35	pF
Reverse Leakage (V _R = 15 V)	I _R	-	10	50	μAdc
Forward Voltage (I _F = 10 mAdc)	V _F	1	0.24	0.27	Vdc
Forward Voltage (I _F = 100 mAdc)	V _F	_	0.30	0.35	Vdc
Forward Voltage (I _F = 900 mAdc)	V _F	-	0.45	0.50	Vdc



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HIGH CURRENT SCHOTTKY BARRIER DIODE

1, 2, 5, 6 • • • 3, 4 CATHODE ANODE



SOT-563 CASE 463A STYLE 5

MARKING DIAGRAM



RD = Specific Device Code

M = Month Code

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
NSR0320XV6T1	SOT-563*	4000/Tape & Reel
NSR0320XV6T1G	SOT-563*	4000/Tape & Reel
NSR0320XV6T5	SOT-563*	8000/Tape & Reel
NSR0320XV6T5G	SOT-563*	8000/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

^{*}This package is inherently Pb-Free.

NSR0320XV6T1

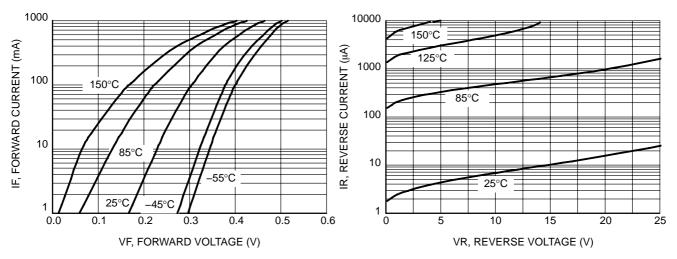


Figure 1. Forward Voltage

Figure 2. Leakage Current

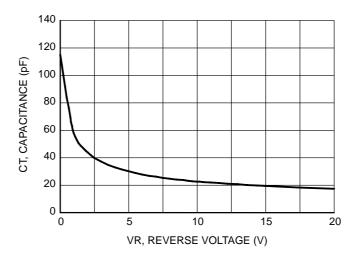


Figure 3. Total Capacitance



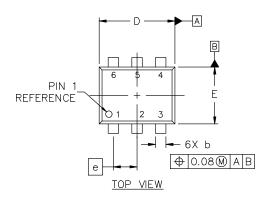


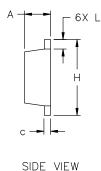
SOT-563-6 1.60x1.20x0.55, 0.50P CASE 463A **ISSUE J**

DATE 15 FEB 2024

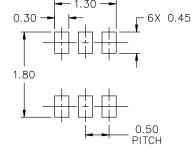
NOTES:

- DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- ALL DIMENSION ARE IN MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.





DIM	MILLIMETERS		
וועם	MIN.	N□M.	MAX.
Α	0.50	0.55	0.60
b	0.17	0.22	0.27
C	0.08	0.13	0.18
D	1.50	1,60	1.70
Е	1.10	1.20	1.30
е	0.50 BSC		
Н	1.50	1.60	1.70
L	0.10	0.20	0.30



STYLE 1:	STYLE 2:	STYLE 3:
PIN 1. EMITTER 1	PIN 1. EMITTER 1	PIN 1. CATHODE 1
2. BASE 1	2. EMITTER 2	2. CATHODE 1
3. COLLECTOR 2	3. BASE 2	3. ANODE/ANODE 2
4. EMITTER 2	4. COLLECTOR 2	4. CATHODE 2
5. BASE 2	5. BASE 1	5. CATHODE 2
6. COLLECTOR 1	6. COLLECTOR 1	6. ANODE/ANODE 1
6. COLLECTOR 1	6. COLLECTOR 1	6. ANDDE/ANDDE 1

STYLE 6: PIN 1. CATHODE 2. ANODE

3. CATHODE

4. CATHODE 5. CATHODE

RECOMMENDED	MOLINTING	FOOTPRINT*
NECOMMENDED	MOONTING	I OO IFIXIIN I .

FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

STYLE 7:	STYLE 8:	STYLE 9:
PIN 1. CATHODE	PIN 1. DRAIN	PIN 1. SOURCE 1
2. ANODE	2. DRAIN	2. GATE 1
3. CATHODE	3. GATE	3. DRAIN 2
4. CATH□DE	4. SOURCE	4. SOURCE 2
5. ANODE	5. DRAIN	5. GATE 2
6. CATH□DE	6. DRAIN	6. DRAIN 1

PIN 1. EMITTER 2

BASE 2

STYLE 11:

2. 3.

5. BASE 1

STYLE 5:

PIN 1. CATHODE

2. CATHODE

4. ANDDE 5. CATHODE

3. ANDDE

GENERIC MARKING DIAGRAM*



XX = Specific Device Code M = Month Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

STYLE 4: PIN 1. COLLECTOR

3. BASE

STYLE 10:

PIN 1. CATHODE 1 2. N/C 3. CATHODE 2

5. N/C

4. ANDDE 2

6. ANDDE 1

2. COLLECTOR

4. EMITTER 5. COLLECTOR

COLLECTOR

COLLECTOR 2 98AON11126D

COLLECTOR 1

EMITTER 1

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DESCRIPTION: SOT-563-6 1.60x1.20x0.55, 0.50P **PAGE 1 OF 1**

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